

Séminaire SOLEIL

Soft-X-Ray ARPES at SLS: Electronic Structure of 3-Dimensional Systems and Buried Heterostructures

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Invité par Antonio TEJEDA

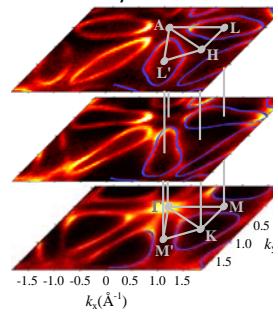
Lundi 12 novembre à 14h00
Grand Amphi SOLEIL

A fundamental benefit of pushing the ARPES experiment into the soft-X-ray energy range is the increasing photoelectron escape depth λ . This gives a boost to bulk sensitivity of ARPES as well as enables access to buried heterostructures. Furthermore, by the Heisenberg uncertainty principle, the increase of λ improves intrinsic resolution in surface-perpendicular momentum $\Delta k_z = \lambda^{-1}$. With free-electron final states and simplified matrix elements achieved in the soft-X-ray energy range, the improved k_z definition enables exploration of electronic structure of 3-dimensional (3D) systems under full control of the 3D momentum \mathbf{k} .

The soft-X-ray ARPES facility at SLS is installed at the ADDRESS beamline [1] which delivers soft-X-ray radiation with variable polarizations in a photon energy range from 300 to 1600 eV. High photon flux topping up 10^{13} photons/s/0.01%BW at 1 keV has taken us through the notorious problem of small valence band cross-section in the soft-X-ray range. At energies around 900 eV, ARPES images of publication quality are routinely acquired within 5 min at a combined energy resolution of 110 meV, and within 30 min at resolution of 60 meV.

Apart from the key technical issues, I give an overview of the most important results achieved with the new facility. They include determination of 3D Fermi surface (FS) of VSe₂ (figure), with out-of-plane warping of the FS giving rise to exotic 3D charge density waves; polarization dependence and alternating FS shapes in pnictide HTSCs, revealing their 3D character and intra-cell interference effects; 3D hybridization between *sp*- and *f*-states in heavy-fermion systems; topological surface state embedded in 3D valence band of PbBi₄Te₇, with spatial oscillations of its wavefunction reflected in photon energy dependence of ARPES intensity; electronic structure of Mn magnetic impurities in 3D host lattice of diluted magnetic semiconductor FS of buried layers in LaNiO₃/LaAlO₃ and SrTiO₃/LaAlO₃ heterostructures, depth localization of 2D electron gas in mixed-valence LaAlO₃/SrTiO₃ systems; standing X-ray waves excited ARPES of BiFeO₃/La_{0.7}Sr_{0.3}MnO₃ multilayer heterostructures allowing depth resolved profiling of its electronic structure; etc. These unfolding results demonstrate an immense potential of soft-X-ray ARPES to deliver a clear view of the electronic structure of 3D systems and buried heterostructures.

[1] V.N. Strocov et al, *J. Synchrotron Rad.* **17**, 631 (2010)



Formalités d'entrée : accès libre dans l'amphi du Pavillon d'Accueil. Si la manifestation a lieu dans le Grand Amphi SOLEIL du Bâtiment Central, merci de vous munir d'une pièce d'identité (à échanger à l'accueil contre un badge d'accès).

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